

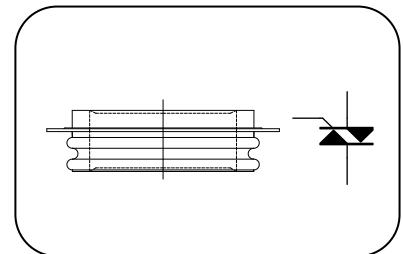
Features:

- Two anti-paralleled thyristors on one Si-wafer
- Hermetic metal cases with ceramic insulators
- Capsule packages for double sided cooling

Typical Applications

- High power industrial and power transmission
- DC and AC motor control
- AC controllers

$I_{T(RMS)}$	830A
V_{DRM}/V_{RRM}	500~1800V
I_{TSM}	7.8 kA
I^2t	304 A ² s*10 ³



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{T(RMS)}$	RMS current	50Hz sine wave Double side cooled,	125			1210	A
						830	
V_{DRM}	Repetitive peak reverse voltage	$t_p=10ms$	125	500		1800	V
I_{DRM}	Repetitive peak current	at V_{DRM}	125			50	mA
I_{TSM}	Surge on-state current	10ms half sine wave $V_R=0.6V_{RRM}$	125			7.8	kA
I^2t	I^2t for fusing coordination					304	A ² s*10 ³
V_{TO}	Threshold voltage		125			1.00	V
r_T	On-state slope resistance					0.85	mΩ
V_{TM}	Peak on-state voltage	$I_{TM}=1200A, F=18kN$	125			2.70	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			50	V/μs
di/dt	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$ to 1000A, Gate pulse $t_r \leq 0.5\mu s$ $I_{GM}=1.5A$ Repetitive	125			50	A/μs
I_{GT}	Gate trigger current	$V_A=12V, I_A=1A$	25	20		350	mA
V_{GT}	Gate trigger voltage			0.8		3.5	V
I_H	Holding current			20		400	mA
$R_{th(j-c)}$	Thermal resistance Junction to case	double side cooled Clamping force 18kN				0.030	°C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.008	
F_m	Mounting force				15	20	kN
T_{stg}	Stored temperature				-40	140	°C
W_t	Weight					200	g
Outline		KA37					

Outline:

